



**THE DATASHEET OF
AP2114D-1.2TRG1**



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

General Description

The AP2114 is CMOS process low dropout linear regulator with enable function, the regulator delivers a guaranteed 1A (Min) continuous load current.

The AP2114 features low power consumption.

The AP2114 is available in 1.2V, 1.5V, 1.8V, 2.5V and 3.3V regulator output and 0.8V to 5V adjustable output, and available in excellent output accuracy $\pm 1.5\%$, it is also available in an excellent load regulation and line regulation performance.

The AP2114 is available in standard packages of SOT-223, TO-252-2(1), TO-252-2(3), TO-252-2(4), TO-263-3, SOIC-8 and PSOP-8.

Features

- Output Voltage Accuracy: $\pm 1.5\%$
- Output Current: 1A (Min)
- Fold-back Short Current Protection: 50mA
- Low Dropout Voltage (3.3V): 450mV (Typ) @ $I_{OUT}=1A$
- Stable with 4.7 μ F Flexible Cap: Ceramic, Tantalum and Aluminum Electrolytic
- Excellent Line Regulation: 0.02%/V (Typ), 0.1%/V (Max) @ $I_{OUT}=30mA$
- Excellent Load Regulation: 0.2%A (Typ) @ $I_{OUT}=1mA$ to 1A
- Low Quiescent Current: 60 μ A (1.2V/1.5V/1.8V /2.5V/ADJ)
- Low Output Noise: 30 μ V_{RMS}
- PSRR: 68dB @ Freq=1KHz(1.2V/1.5V/1.8V /ADJ)
- OTSD Protection
- Operating Temperature Range: -40°C to 85°C
- ESD: MM 400V, HBM 4000V

Applications

- LCD Monitor
- LCD TV
- STB

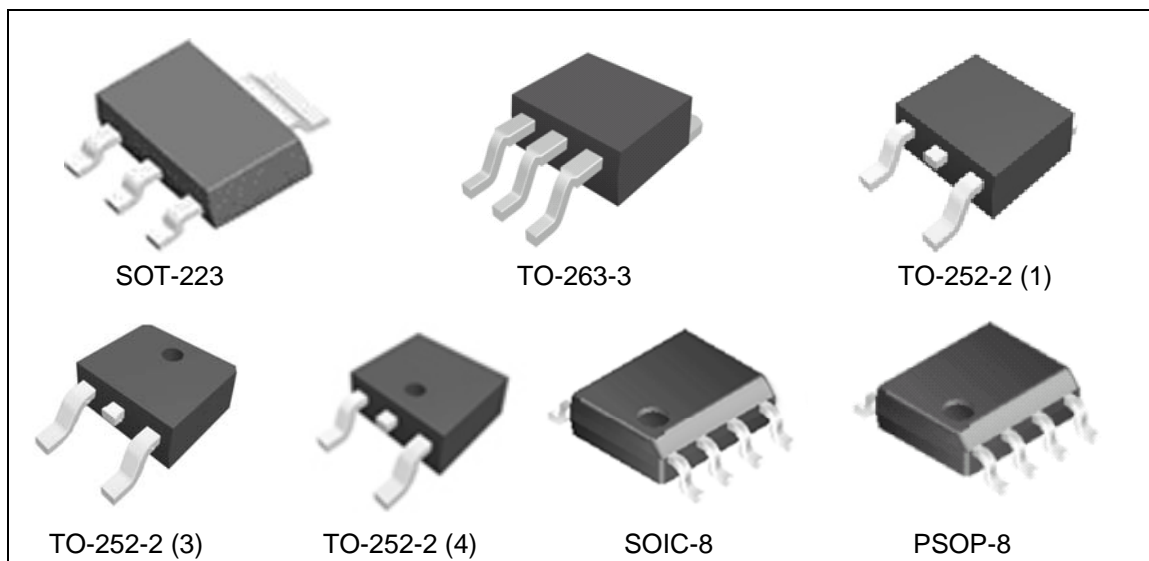


Figure 1. Package Types of AP2114

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Pin Configuration

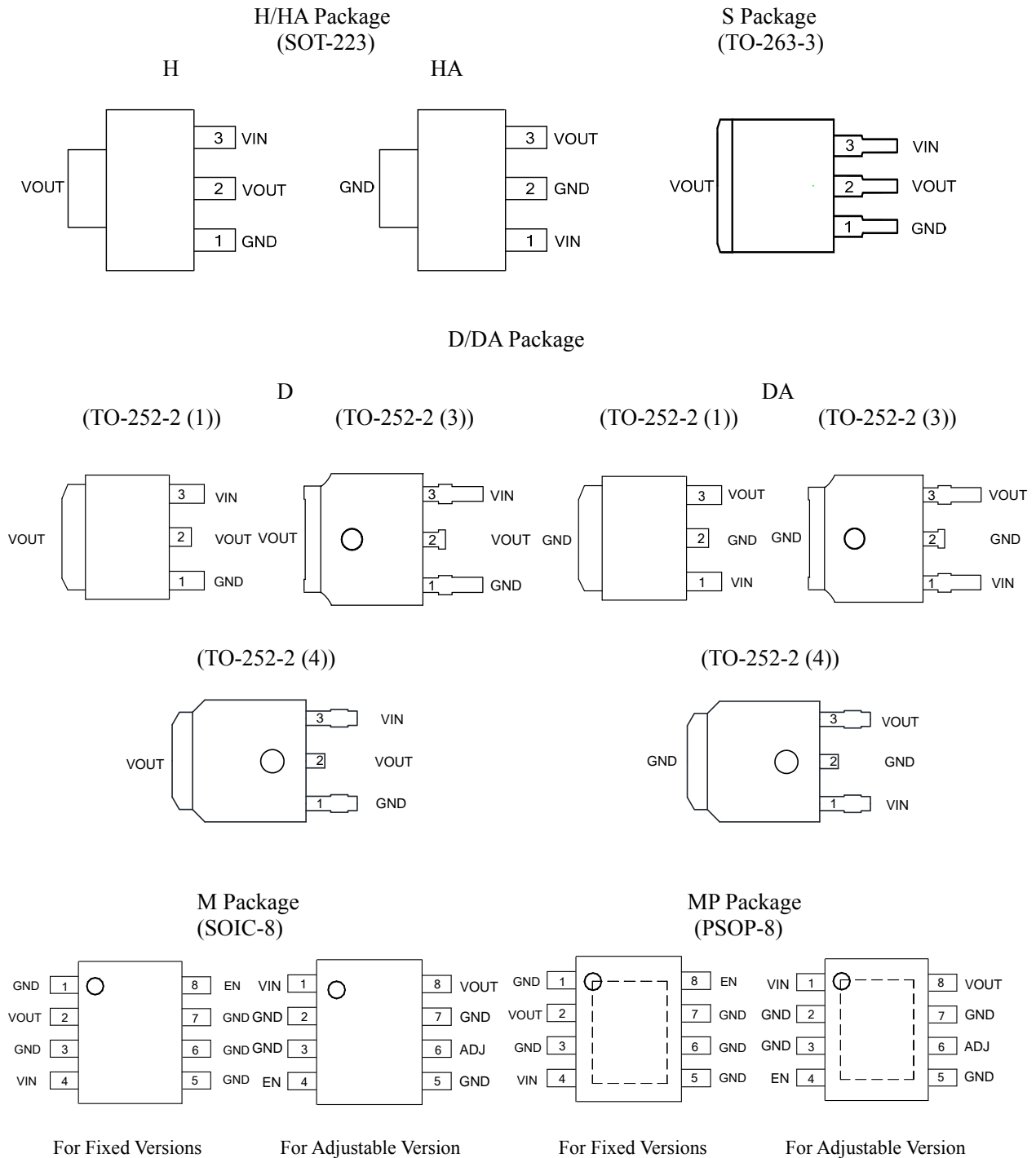


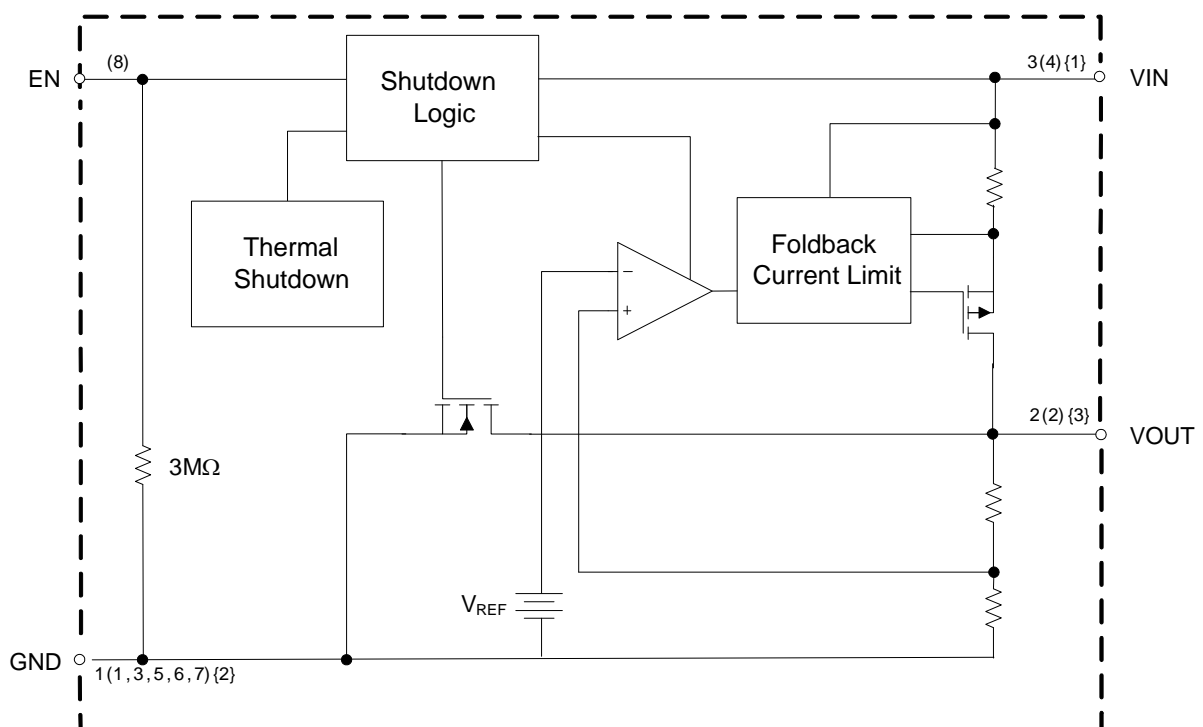
Figure 2. Pin Configuration of AP2114 (Top View)

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Pin Descriptions

| Pin Number | | | | Pin Name | Function |
|---|--|------------------------------|----------------------------|----------|--|
| SOT-223 (H), TO-263-3, TO-252-2 (1) (D) TO-252-2 (3) (D) TO-252-2 (4) (D) | SOT-223 (HA), TO-252-2 (1) (DA) TO-252-2 (3) (DA) TO-252-2 (4) (DA) | SOIC-8, PSOP-8 (Fixed) | SOIC-8, PSOP-8 (ADJ) | | |
| 1 | 2 | 1, 3, 5, 6, 7 | 2, 3, 5, 7 | GND | Ground |
| 2 | 3 | 2 | 8 | VOUT | Regulated Output |
| 3 | 1 | 4 | 1 | VIN | Input Voltage Pin |
| | | 8 | 4 | EN | Chip Enable, H-Normal Work, L- Shutdown Output |
| | | | 6 | ADJ | Adjust Output |

Functional Block Diagram

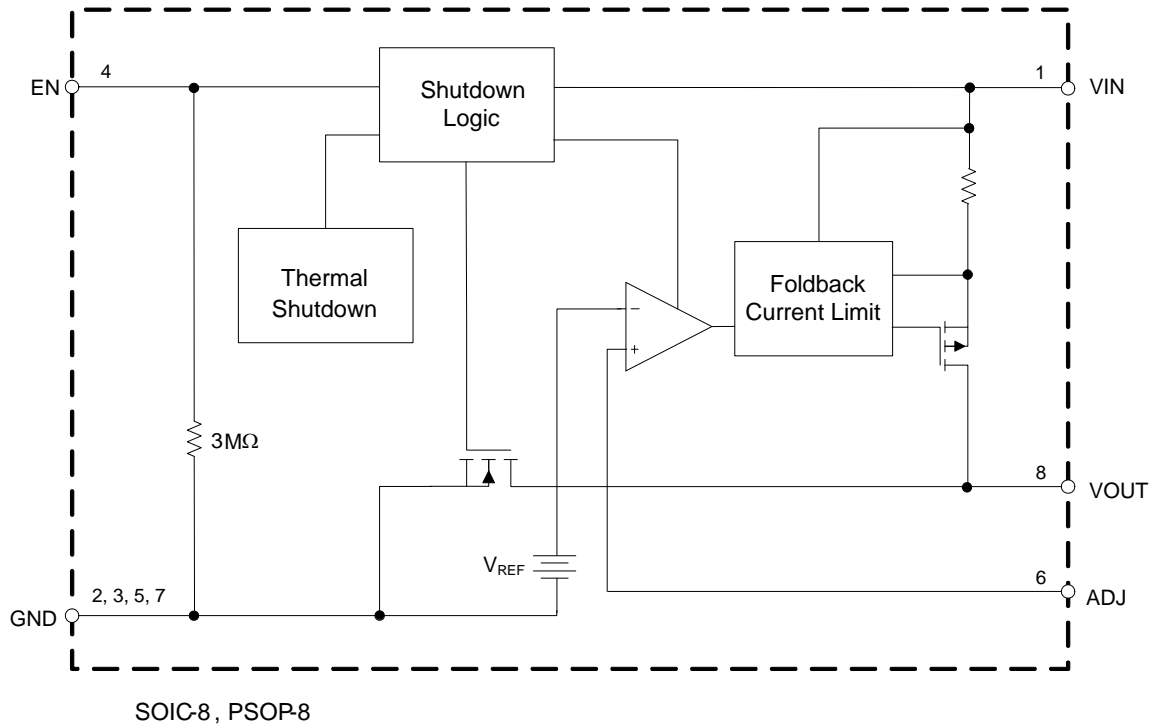


A(B){C}
 A: SOT-223(H), TO-263-3, TO-252-2(1)/(3)/(4)(D)
 B: SOIC-8, PSOP-8
 C: SOT-223 (HA), TO-252-2(1)/(3)/(4)(DA)

For Fixed Versions

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Functional Block Diagram (Continued)

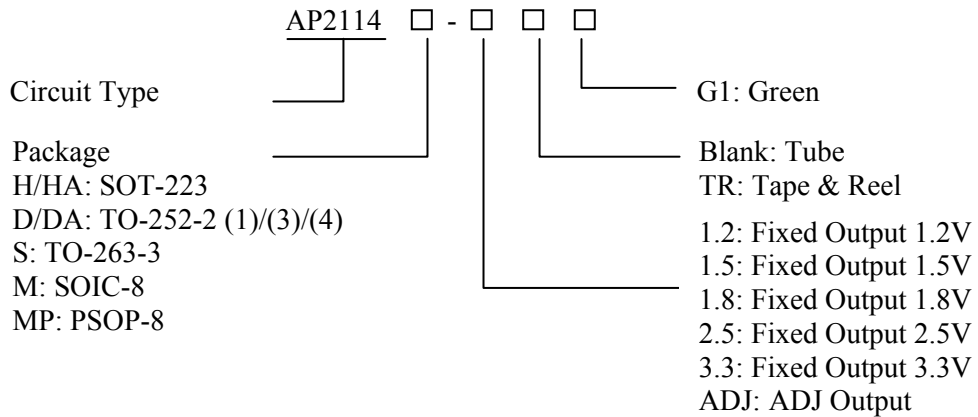


For ADJ Version

Figure 3. Functional Block Diagram of AP2114

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Ordering Information



| Package | Temperature Range | Output Voltage | Part Number | Marking ID | Packing Type |
|--|-------------------|-----------------|------------------|----------------|--------------|
| SOT-223 | -40 to 85°C | 1.2V (H) | AP2114H-1.2TRG1 | GH12C | Tape & Reel |
| | | 1.5V (H) | AP2114H-1.5TRG1 | GH16G | Tape & Reel |
| | | 1.8V (H) | AP2114H-1.8TRG1 | GH12D | Tape & Reel |
| | | 2.5V (H) | AP2114H-2.5TRG1 | GH14C | Tape & Reel |
| | | 3.3V (H) | AP2114H-3.3TRG1 | GH12E | Tape & Reel |
| SOT-223 | -40 to 85°C | 1.2V (HA) | AP2114HA-1.2TRG1 | GH13B | Tape & Reel |
| | | 1.5V (HA) | AP2114HA-1.5TRG1 | GH16H | Tape & Reel |
| | | 1.8V (HA) | AP2114HA-1.8TRG1 | GH14D | Tape & Reel |
| | | 2.5V (HA) | AP2114HA-2.5TRG1 | GH14E | Tape & Reel |
| | | 3.3V (HA) | AP2114HA-3.3TRG1 | GH14F | Tape & Reel |
| TO-252-2 (1)/ TO-252-2 (3)/ TO-252-2 (4) | -40 to 85°C | 1.2V (D) | AP2114D-1.2TRG1 | AP2114D-1.2G1 | Tape & Reel |
| | | 1.5V (D) | AP2114D-1.5TRG1 | AP2114D-1.5G1 | Tape & Reel |
| | | 1.8V (D) | AP2114D-1.8TRG1 | AP2114D-1.8G1 | Tape & Reel |
| | | 2.5V (D) | AP2114D-2.5TRG1 | AP2114D-2.5G1 | Tape & Reel |
| | | 3.3V (D) | AP2114D-3.3TRG1 | AP2114D-3.3G1 | Tape & Reel |
| TO-252-2 (1)/ TO-252-2 (3)/ TO-252-2 (4) | -40 to 85°C | 1.2V (DA) | AP2114DA-1.2TRG1 | AP2114DA-1.2G1 | Tape & Reel |
| | | 1.5V (DA) | AP2114DA-1.5TRG1 | AP2114DA-1.5G1 | Tape & Reel |
| | | 1.8V (DA) | AP2114DA-1.8TRG1 | AP2114DA-1.8G1 | Tape & Reel |
| | | 2.5V (DA) | AP2114DA-2.5TRG1 | AP2114DA-2.5G1 | Tape & Reel |
| | | 3.3V (DA) | AP2114DA-3.3TRG1 | AP2114DA-3.3G1 | Tape & Reel |
| TO-263-3 | -40 to 85°C | 1.2V | AP2114S-1.2TRG1 | AP2114S-1.2G1 | Tape & Reel |
| | | 1.5V | AP2114S-1.5TRG1 | AP2114S-1.5G1 | Tape & Reel |
| | | 1.8V | AP2114S-1.8TRG1 | AP2114S-1.8G1 | Tape & Reel |
| | | 2.5V | AP2114S-2.5TRG1 | AP2114S-2.5G1 | Tape & Reel |
| | | 3.3V | AP2114S-3.3TRG1 | AP2114S-3.3G1 | Tape & Reel |
| SOIC-8 | -40 to 85°C | 1.2V | AP2114M-1.2TRG1 | 2114M-1.2G1 | Tape & Reel |
| | | 1.5V | AP2114M-1.5TRG1 | 2114M-1.5G1 | Tape & Reel |
| | | 1.8V | AP2114M-1.8TRG1 | 2114M-1.8G1 | Tape & Reel |
| | | 2.5V | AP2114M-2.5TRG1 | 2114M-2.5G1 | Tape & Reel |
| | | 3.3V | AP2114M-3.3TRG1 | 2114M-3.3G1 | Tape & Reel |
| | | ADJ | AP2114M-ADJG1 | 2114M-ADJG1 | Tube |
| | | AP2114M-ADJTRG1 | 2114M-ADJG1 | Tape & Reel | |

**1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114****Ordering Information (Continued)**

| Package | Temperature Range | Output Voltage | Part Number | Marking ID | Packing Type |
|---------|-------------------|----------------|------------------|--------------|--------------|
| PSOP-8 | -40 to 85°C | 1.2V | AP2114MP-1.2TRG1 | 2114MP-1.2G1 | Tape & Reel |
| | | 1.5V | AP2114MP-1.5TRG1 | 2114MP-1.5G1 | Tape & Reel |
| | | 1.8V | AP2114MP-1.8TRG1 | 2114MP-1.8G1 | Tape & Reel |
| | | 2.5V | AP2114MP-2.5TRG1 | 2114MP-2.5G1 | Tape & Reel |
| | | 3.3V | AP2114MP-3.3TRG1 | 2114MP-3.3G1 | Tape & Reel |
| | | ADJ | AP2114MP-ADJG1 | 2114MP-ADJG1 | Tube |
| | | | AP2114MP-ADJTRG1 | 2114MP-ADJG1 | Tape & Reel |

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and Green.

**1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114****Absolute Maximum Ratings (Note 1)**

| Parameter | Symbol | Value | | Unit |
|--|---------------|--|-----|------|
| Power Supply Voltage | V_{IN} | 6.5 | | V |
| Operating Junction Temperature Range | T_J | 150 | | °C |
| Storage Temperature Range | T_{STG} | -65 to 150 | | °C |
| Lead Temperature (Soldering, 10sec) | T_{LEAD} | 260 | | °C |
| Thermal Resistance (Junction to Ambient) (No Heatsink) | θ_{JA} | SOIC-8 | 144 | °C/W |
| | | PSOP-8 | 143 | |
| | | SOT-223 | 128 | |
| | | TO-252-2 (1)/ TO-252-2 (3)/ TO-252-2 (4) | 90 | |
| | | TO-263-3 | 73 | |
| ESD (Machine Model) | | 400 | | V |
| ESD (Human Body Model) | | 4000 | | V |

Note 1: Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “Recommended Operating Conditions” is not implied. Exposure to “Absolute Maximum Ratings” for extended periods may affect device reliability.

Recommended Operating Conditions

| Parameter | Symbol | Min | Max | Unit |
|-------------------------------------|----------|-----|-----|------|
| Supply Voltage | V_{IN} | 2.5 | 6.0 | V |
| Operating Ambient Temperature Range | T_A | -40 | 85 | °C |



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics

AP2114-1.2 Electrical Characteristics (Note 2)

($V_{IN}=2.5V$, $C_{IN}=4.7\mu F$ (Ceramic), $C_{OUT}=4.7\mu F$ (Ceramic), Typical $T_A=25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_A \leq 85^\circ C$ ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|--|---------------------------------|----------------------------|----------------------------------|-----------------|
| Output Voltage | V_{OUT} | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 30mA$ | $\frac{V_{OUT}}{\times 98.5\%}$ | 1.2 | $\frac{V_{OUT}}{\times 101.5\%}$ | V |
| Input Voltage | V_{IN} | | | | 6.0 | V |
| Maximum Output Current | $I_{OUT(MAX)}$ | $V_{IN}=2.5V$, $V_{OUT}=1.182V$ to $1.218V$ | 1 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 1A$ | | 0.2 | 1 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | $2.5V \leq V_{IN} \leq 6V$, $I_{OUT}=30mA$ | -0.1 | 0.02 | 0.1 | %/V |
| Dropout Voltage | V_{DROP} | $I_{OUT}=1.0A$ | | 1200 | 1300 | mV |
| Quiescent Current | I_Q | $V_{IN}=2.5V$, $I_{OUT}=0mA$ | | 60 | 75 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p $V_{IN}=2.5V$, $I_{OUT}=100mA$ | $f=100Hz$ | 68 | | dB |
| | | | $f=1KHz$ | 68 | | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | $I_{OUT}=30mA$, $T_A = -40^\circ C$ to $85^\circ C$ | | ± 30 | | ppm/ $^\circ C$ |
| Short Current Limit | I_{SHORT} | $V_{OUT}=0V$ | | 50 | | mA |
| RMS Output Noise | V_{NOISE} | $10Hz \leq f \leq 100kHz$ (No Load) | | 30 | | μV_{RMS} |
| V_{EN} High Voltage | V_{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V_{EN} Low Voltage | V_{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I_{STD} | $V_{IN}=2.5V$, V_{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t_s | No Load | | 20 | | μs |
| EN Pull Down Resistor | R_{PD} | | | 3.0 | | M Ω |
| V_{OUT} Discharge Resistor | R_{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T_{OTSD} | | | 160 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ_{JC} | SOIC-8 | | 74.6 | | $^\circ C/W$ |
| | | PSOP-8 | | 43.7 | | |
| | | SOT-223 | | 50.9 | | |
| | | TO-252-2 (1)/(3)/(4) | | 35 | | |
| | | TO-263-3 | | 22 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at $T_A=25^\circ C$. Over temperature specifications guaranteed by design only.



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics (Continued)

AP2114-1.5 Electrical Characteristics (Note 2)

($V_{IN}=2.5V$, $C_{IN}=4.7\mu F$ (Ceramic), $C_{OUT}=4.7\mu F$ (Ceramic), Typical $T_A=25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_A \leq 85^\circ C$ ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|--|---------------------------------|----------------------------|----------------------------------|-----------------|
| Output Voltage | V_{OUT} | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 30mA$ | $\frac{V_{OUT}}{\times 98.5\%}$ | 1.5 | $\frac{V_{OUT}}{\times 101.5\%}$ | V |
| Input Voltage | V_{IN} | | | | 6.0 | V |
| Maximum Output Current | $I_{OUT(MAX)}$ | $V_{IN}=2.5V$, $V_{OUT}=1.478V$ to $1.523V$ | 1 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 1A$ | | 0.2 | 1 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | $2.5V \leq V_{IN} \leq 6V$, $I_{OUT}=30mA$ | -0.1 | 0.02 | 0.1 | %/V |
| Dropout Voltage | V_{DROP} | $I_{OUT}=1.0A$ | | 800 | 1000 | mV |
| Quiescent Current | I_Q | $V_{IN}=2.5V$, $I_{OUT}=0mA$ | | 60 | 75 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p $V_{IN}=2.5V$, $I_{OUT}=100mA$ | $f=100Hz$ | 68 | | dB |
| | | | $f=1KHz$ | 68 | | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | $I_{OUT}=30mA$, $T_A = -40^\circ C$ to $85^\circ C$ | | ± 30 | | ppm/ $^\circ C$ |
| Short Current Limit | I_{SHORT} | $V_{OUT}=0V$ | | 50 | | mA |
| RMS Output Noise | V_{NOISE} | $10Hz \leq f \leq 100kHz$ (No Load) | | 30 | | μV_{RMS} |
| V_{EN} High Voltage | V_{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V_{EN} Low Voltage | V_{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I_{STD} | $V_{IN}=2.5V$, V_{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t_s | No Load | | 20 | | μs |
| EN Pull Down Resistor | R_{PD} | | | 3.0 | | M Ω |
| V_{OUT} Discharge Resistor | R_{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T_{OTSD} | | | 160 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ_{JC} | SOIC-8 | | 74.6 | | $^\circ C/W$ |
| | | PSOP-8 | | 43.7 | | |
| | | SOT-223 | | 50.9 | | |
| | | TO-252-2 (1)/(3)/(4) | | 35 | | |
| | | TO-263-3 | | 22 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at $T_A=25^\circ C$. Over temperature specifications guaranteed by design only.



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics (Continued)

AP2114-1.8 Electrical Characteristics (Note 2)

($V_{IN}=2.8V$, $C_{IN}=4.7\mu F$ (Ceramic), $C_{OUT}=4.7\mu F$ (Ceramic), Typical $T_A=25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_A \leq 85^\circ C$ ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|--|-------------------------|----------------------------|--------------------------|-----------------|
| Output Voltage | V_{OUT} | $V_{IN}=2.8V$, $1mA \leq I_{OUT} \leq 30mA$ | $V_{OUT} \times 98.5\%$ | 1.8 | $V_{OUT} \times 101.5\%$ | V |
| Maximum Output Current | $I_{OUT(MAX)}$ | $V_{IN}=2.8V$, $V_{OUT}=1.773V$ to $1.827V$ | 1.0 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | $V_{IN}=2.8V$, $1mA \leq I_{OUT} \leq 1A$ | | 0.2 | 1.0 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | $2.8V \leq V_{IN} \leq 6V$, $I_{OUT}=30mA$ | -0.1 | 0.02 | 0.1 | %/V |
| Dropout Voltage | V_{DROP} | $I_{OUT}=1.0A$ | | 500 | 700 | mV |
| Quiescent Current | I_Q | $V_{IN}=2.8V$, $I_{OUT}=0mA$ | | 60 | 75 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p $V_{IN}=2.8V$, $I_{OUT}=100mA$ | $f=100Hz$ | | 68 | dB |
| | | | $f=1KHz$ | | 68 | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | $I_{OUT}=30mA$, $T_A = -40^\circ C$ to $85^\circ C$ | | ± 30 | | ppm/ $^\circ C$ |
| Short Current Limit | I_{SHORT} | $V_{OUT}=0V$ | | 50 | | mA |
| RMS Output Noise | V_{NOISE} | $10Hz \leq f \leq 100kHz$ (No load) | | 30 | | μV_{RMS} |
| V_{EN} High Voltage | V_{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V_{EN} Low Voltage | V_{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I_{STD} | $V_{IN}=2.8V$, V_{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t_S | No Load | | 20 | | μs |
| EN Pull Down Resistor | R_{PD} | | | 3.0 | | M Ω |
| V_{OUT} Discharge Resistor | R_{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T_{OTSD} | | | 160 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ_{JC} | SOIC-8 | | 74.6 | | $^\circ C / W$ |
| | | PSOP-8 | | 43.7 | | |
| | | SOT-223 | | 50.9 | | |
| | | TO-252-2 (1)/(3)/(4) | | 35 | | |
| | | TO-263-3 | | 22 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at $T_A=25^\circ C$. Over temperature specifications guaranteed by design only.



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics (Continued)

AP2114-2.5 Electrical Characteristics (Note 2)

($V_{IN}=3.5V$, $C_{IN}=4.7\mu F$ (Ceramic), $C_{OUT}=4.7\mu F$ (Ceramic), Typical $T_A=25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_A \leq 85^\circ C$ ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|--|-------------------------|----------------------------|--------------------------|-----------------|
| Output Voltage | V_{OUT} | $V_{IN}=3.5V$, $1mA \leq I_{OUT} \leq 30mA$ | $V_{OUT} \times 98.5\%$ | 2.5 | $V_{OUT} \times 101.5\%$ | V |
| Maximum Output Current | $I_{OUT(MAX)}$ | $V_{IN}=3.5V$, $V_{OUT}=2.463V$ to $2.537V$ | 1.0 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | $V_{out}=2.5V$, $V_{IN}=V_{out}+1V$ $1mA \leq I_{OUT} \leq 1A$ | | 0.2 | 1.0 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | $3.5V \leq V_{IN} \leq 6V$, $I_{OUT}=30mA$ | -0.1 | 0.02 | 0.1 | %/V |
| Dropout Voltage | V_{DROP} | $I_{OUT}=1A$ | | 450 | 750 | mV |
| Quiescent Current | I_Q | $V_{IN}=3.5V$, $I_{OUT}=0mA$ | | 60 | 80 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p $V_{IN}=3.5V$, $I_{OUT}=100mA$ | $f=100Hz$ | 65 | | dB |
| | | | $f=1KHz$ | 65 | | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | $I_{OUT}=30mA$ | | ± 30 | | ppm/ $^\circ C$ |
| Short Current Limit | I_{SHORT} | $V_{OUT}=0V$ | | 50 | | mA |
| RMS Output Noise | V_{NOISE} | $10Hz \leq f \leq 100kHz$ | | 30 | | μV_{RMS} |
| V_{EN} High Voltage | V_{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V_{EN} Low Voltage | V_{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I_{STD} | $V_{IN}=3.5V$, V_{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t_s | No Load | | 20 | | μs |
| EN Pull Down Resistor | R_{PD} | | | 3.0 | | M Ω |
| V_{OUT} Discharge Resistor | R_{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T_{OTSD} | | | 160 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ_{JC} | SOIC-8 | | 74.6 | | $^\circ C/W$ |
| | | PSOP-8 | | 43.7 | | |
| | | SOT-223 | | 50.9 | | |
| | | TO-252-2 (1)/(3)/(4) | | 35 | | |
| | | TO-263-3 | | 22 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at $T_A=25^\circ C$. Over temperature specifications guaranteed by design only.



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics (Continued)

AP2114-3.3 Electrical Characteristics (Note 2)

(V_{IN}=4.3V, C_{IN}=4.7μF (Ceramic), C_{OUT}=4.7μF (Ceramic), Typical T_A= 25°C, **Bold** typeface applies over -40°C≤T_A≤85°C ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|---|----------------------------|------------|-----------------------------|-------------------|
| Output Voltage | V _{OUT} | V _{IN} =4.3V, 1mA ≤ I _{OUT} ≤ 30mA | V _{OUT} ×98.5% | 3.3 | V _{OUT} ×101.5% | V |
| Maximum Output Current | I _{OUT(MAX)} | V _{IN} =4.3V, V _{OUT} =3.25V to 3.35V | 1.0 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | V _{IN} =4.3V, 1mA ≤ I _{OUT} ≤ 1A | | 0.2 | 1.0 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | 4.3V ≤ V _{IN} ≤ 6V, I _{OUT} =30mA | -0.1 | 0.02 | 0.1 | %/V |
| Dropout Voltage | V _{DROP} | I _{OUT} =1A | | 450 | 750 | mV |
| Quiescent Current | I _Q | V _{IN} =4.3V, I _{OUT} =0mA | | 65 | 90 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p V _{IN} =4.3V, I _{OUT} =100mA | f=100Hz | 65 | | dB |
| | | | f=1KHz | 65 | | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | I _{OUT} =30mA | | ±30 | | ppm/°C |
| Short Current Limit | I _{SHORT} | V _{OUT} =0V | | 50 | | mA |
| RMS Output Noise | V _{NOISE} | 10Hz ≤ f ≤ 100kHz (No load) | | 30 | | μV _{RMS} |
| V _{EN} High Voltage | V _{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V _{EN} Low Voltage | V _{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I _{STD} | V _{IN} =4.3V, V _{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t _s | No Load | | 20 | | μs |
| EN Pull Down Resistor | R _{PD} | | | 3.0 | | MΩ |
| V _{OUT} Discharge Resistor | R _{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T _{OTSD} | | | 160 | | °C |
| Thermal Shutdown Hysteresis | T _{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ _{JC} | SOIC-8 | | 74.6 | | °C/W |
| | | PSOP-8 | | 43.7 | | |
| | | SOT-223 | | 50.9 | | |
| | | TO-252-2 (1)/(3)/(4) | | 35 | | |
| | | TO-263-3 | | 22 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at T_A=25°C. Over temperature specifications guaranteed by design only.



1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Electrical Characteristics (Continued)

AP2114-ADJ Electrical Characteristics (Note 2)

($V_{IN}=2.5V$, $C_{IN}=4.7\mu F$ (Ceramic), $C_{OUT}=4.7\mu F$ (Ceramic), Typical $T_A=25^\circ C$, **Bold** typeface applies over $-40^\circ C \leq T_A \leq 85^\circ C$ ranges, unless otherwise specified (Note 3))

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|---|--|---------------------------------|----------------------------|----------------------------------|-----------------|
| Reference Voltage | V_{REF} | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 30mA$ | $\frac{V_{REF}}{\times 98.5\%}$ | 0.8 | $\frac{V_{REF}}{\times 101.5\%}$ | V |
| Input Voltage | V_{IN} | | | | 6.0 | V |
| Maximum Output Current | $I_{OUT(MAX)}$ | $V_{IN}=2.5V$, $V_{OUT}=0.788V$ to $0.812V$ | 1 | | | A |
| Load Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$ | $V_{IN}=2.5V$, $1mA \leq I_{OUT} \leq 1A$ | | 0.2 | 1 | %/A |
| Line Regulation | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$ | $2.5V \leq V_{IN} \leq 6V$, $I_{OUT}=30mA$ | -0.1 | 0.02 | 0.1 | %/V |
| Quiescent Current | I_Q | $V_{IN}=2.5V$, $I_{OUT}=0mA$ | | 60 | 75 | μA |
| Power Supply Rejection Ratio | PSRR | Ripple 1Vp-p $V_{IN}=2.5V$, $I_{OUT}=100mA$ | $f=100Hz$ | | 68 | dB |
| | | | $f=1KHz$ | | 68 | |
| Output Voltage Temperature Coefficient | $\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$ | $I_{OUT}=30mA$, $T_A = -40^\circ C$ to $85^\circ C$ | | ± 30 | | ppm/ $^\circ C$ |
| Short Current Limit | I_{SHORT} | $V_{OUT}=0V$ | | 50 | | mA |
| RMS Output Noise | V_{NOISE} | $10Hz \leq f \leq 100kHz$ (No Load) | | 30 | | μV_{RMS} |
| V_{EN} High Voltage | V_{IH} | Enable logic high, regulator on | 1.5 | | | V |
| V_{EN} Low Voltage | V_{IL} | Enable logic low, regulator off | | | 0.4 | |
| Standby Current | I_{STD} | $V_{IN}=2.5V$, V_{EN} in OFF mode | | 0.01 | 1.0 | μA |
| Start-up Time | t_s | No Load | | 20 | | μs |
| EN Pull Down Resistor | R_{PD} | | | 3.0 | | M Ω |
| V_{OUT} Discharge Resistor | R_{DCHG} | Set EN pin at Low | | 60 | | Ω |
| Thermal Shutdown Temperature | T_{OTSD} | | | 160 | | $^\circ C$ |
| Thermal Shutdown Hysteresis | T_{HYOTSD} | | | 25 | | |
| Thermal Resistance (Junction to Case) | θ_{JC} | SOIC-8 | | 74.6 | | $^\circ C/W$ |
| | | PSOP-8 | | 43.7 | | |

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at $T_A=25^\circ C$. Over temperature specifications guaranteed by design only.

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics

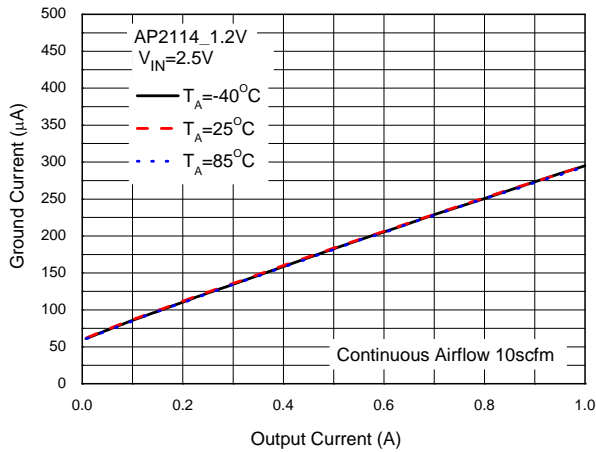


Figure 4. Ground Current vs. Output Current

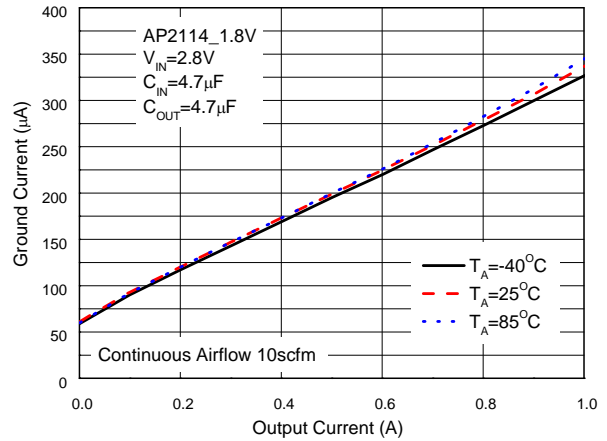


Figure 5. Ground Current vs. Output Current

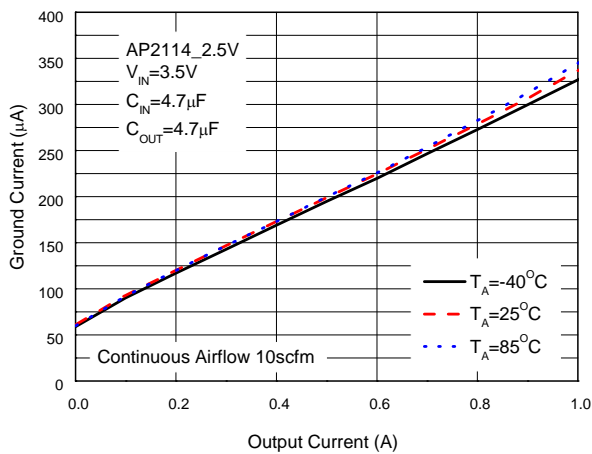


Figure 6. Ground Current vs. Output Current

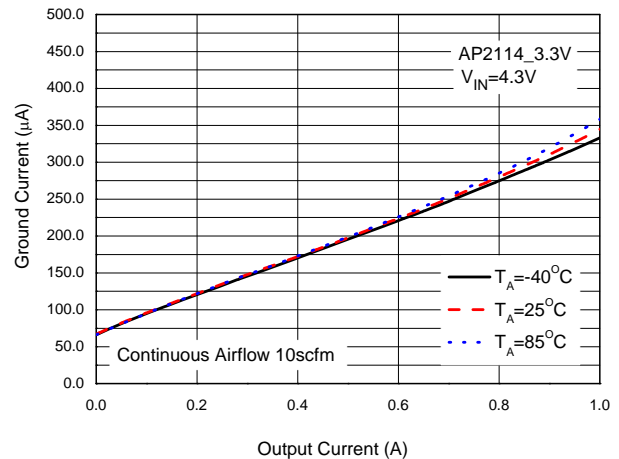


Figure 7. Ground Current vs. Output Current

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

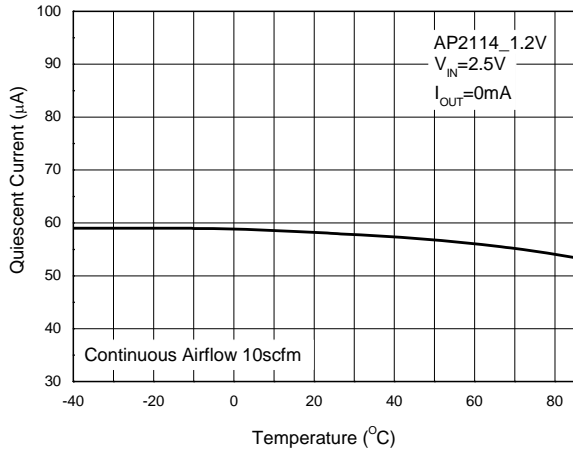


Figure 8. Quiescent Current vs. Temperature

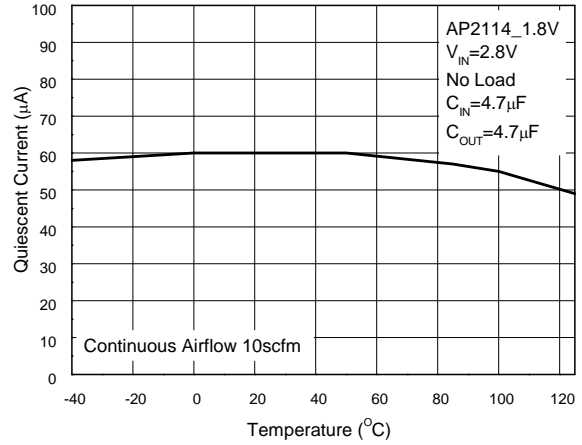


Figure 9. Quiescent Current vs. Temperature

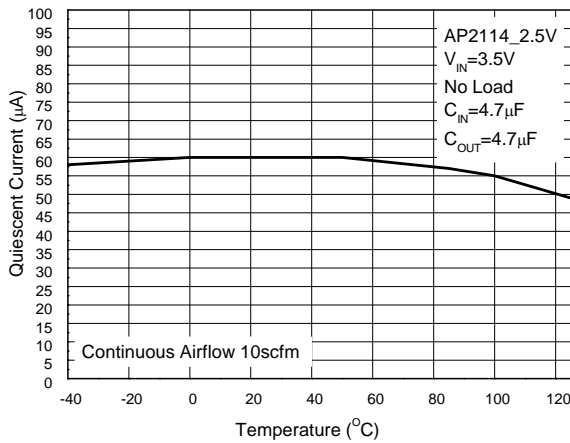


Figure 10. Quiescent Current vs. Temperature

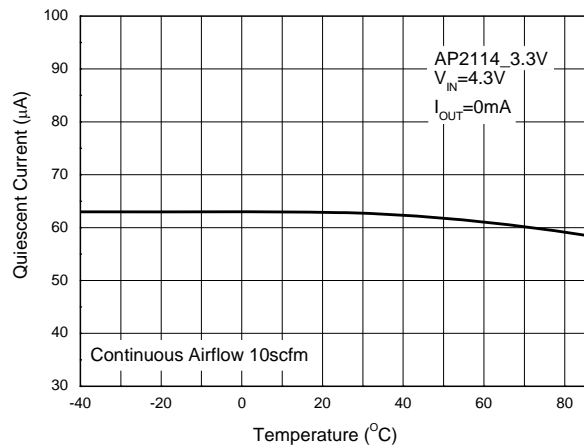


Figure 11. Quiescent Current vs. Temperature

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

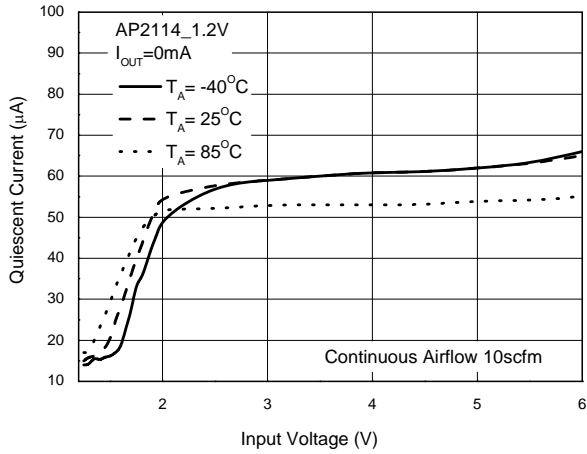


Figure 12. Quiescent Current vs. Input Voltage

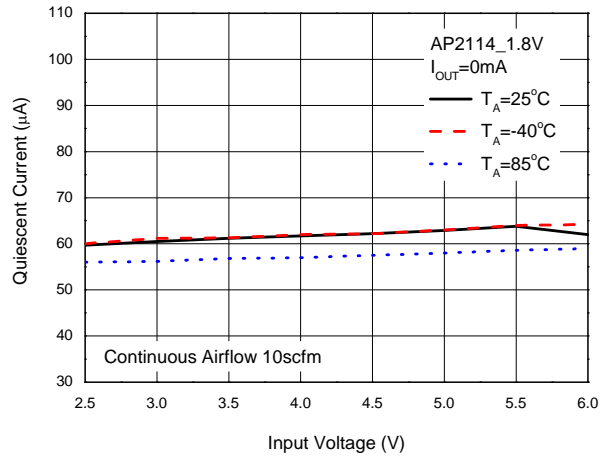


Figure 13. Quiescent Current vs. Input Voltage

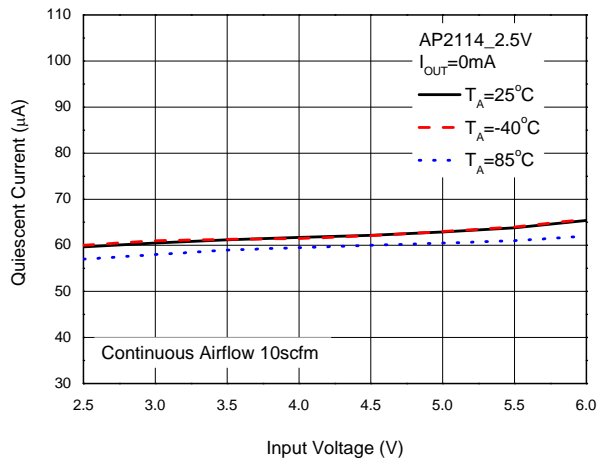


Figure 14. Quiescent Current vs. Input Voltage

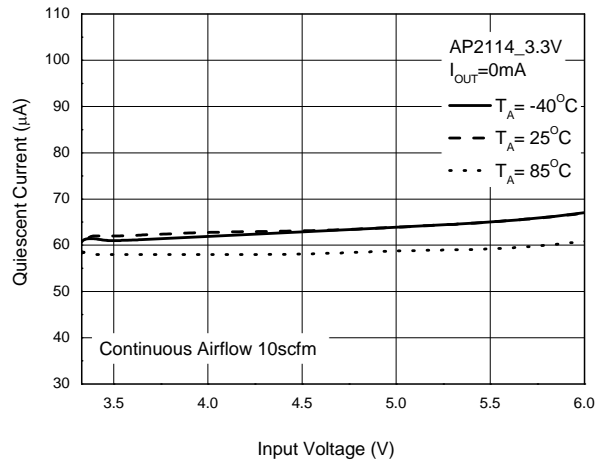


Figure 15. Quiescent Current vs. Input Voltage

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

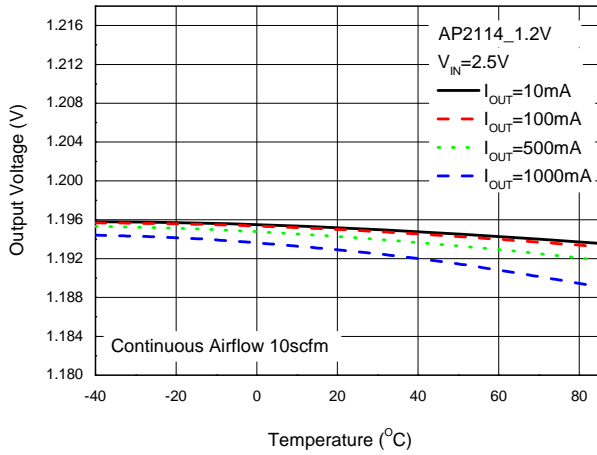


Figure 16. Output Voltage vs. Temperature

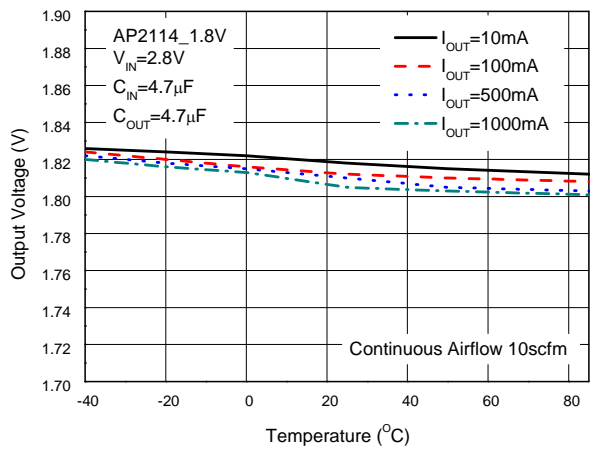


Figure 17. Output Voltage vs. Temperature

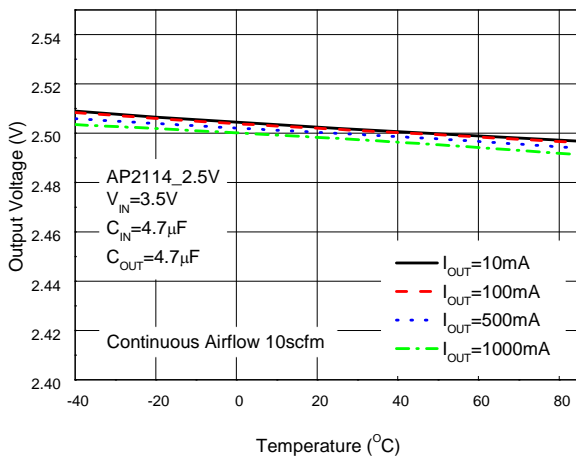


Figure 18. Output Voltage vs. Temperature

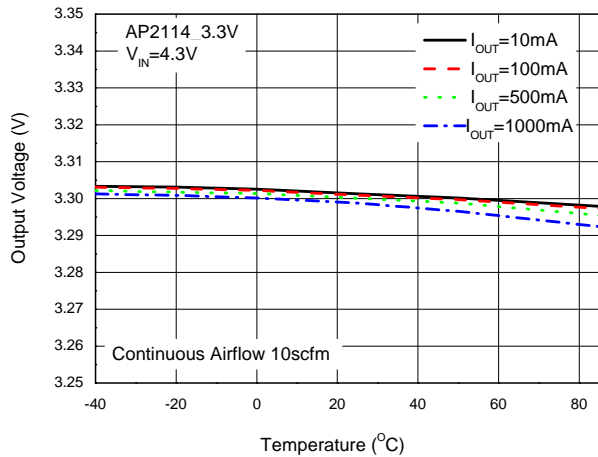


Figure 19. Output Voltage vs. Temperature

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

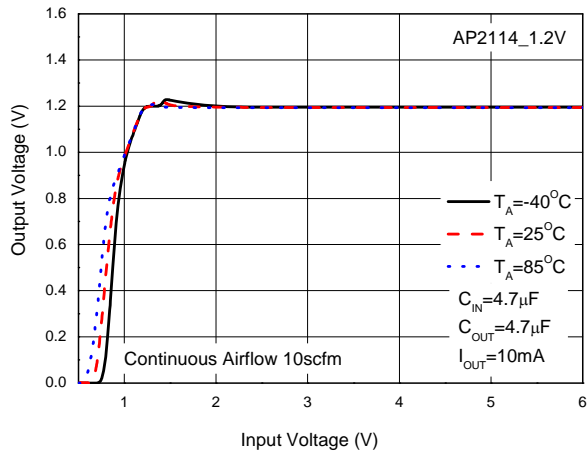


Figure 20. Output Voltage vs. Input Voltage

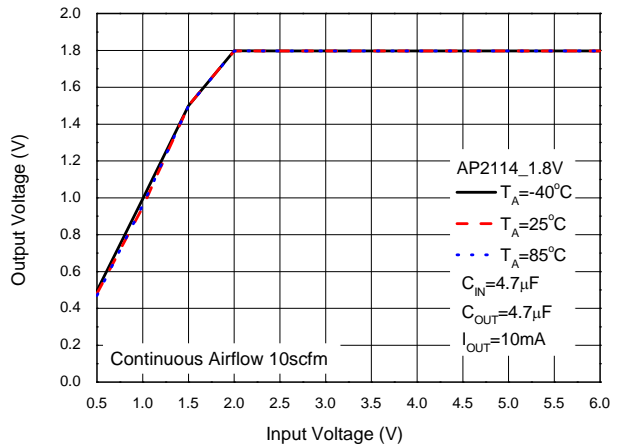


Figure 21. Output Voltage vs. Input Voltage

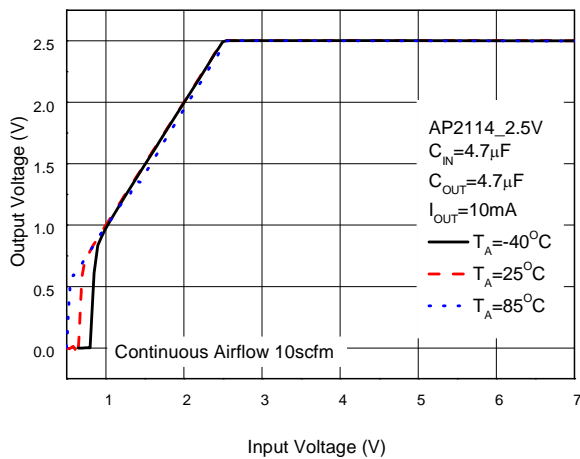


Figure 22. Output Voltage vs. Input Voltage

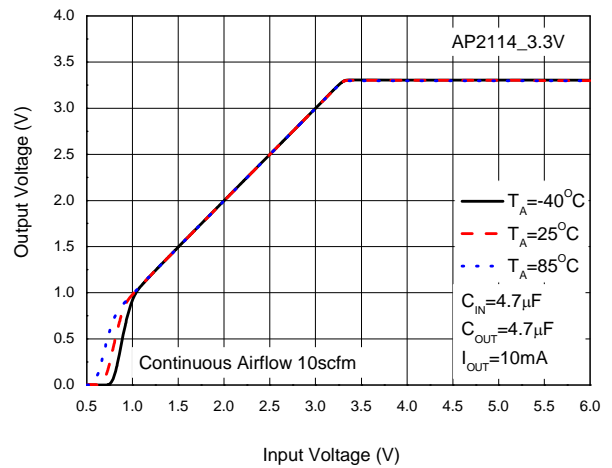


Figure 23. Output Voltage vs. Input Voltage

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

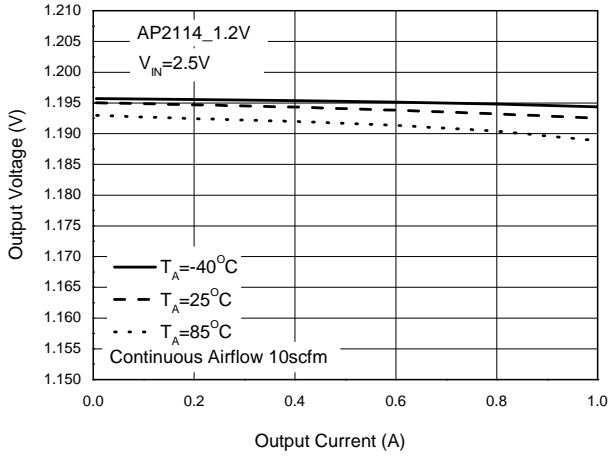


Figure 24. Output Voltage vs. Output Current

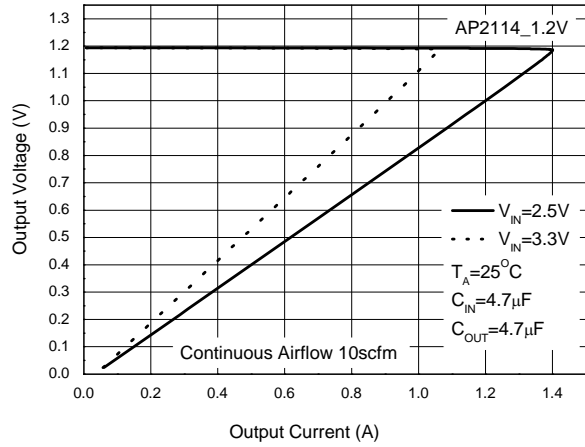


Figure 25. Output Voltage vs. Output Current

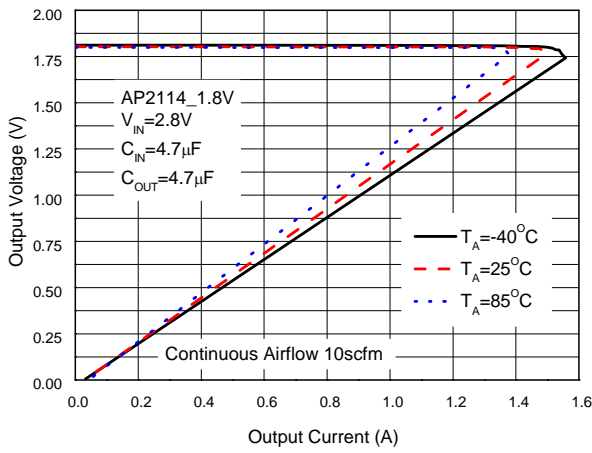


Figure 26. Output Voltage vs. Output Current

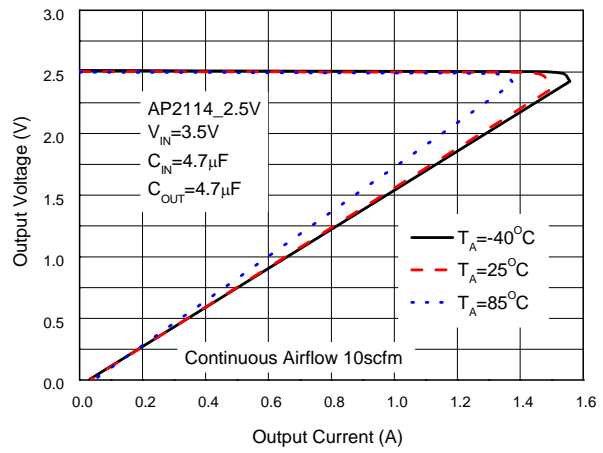


Figure 27. Output Voltage vs. Output Current

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

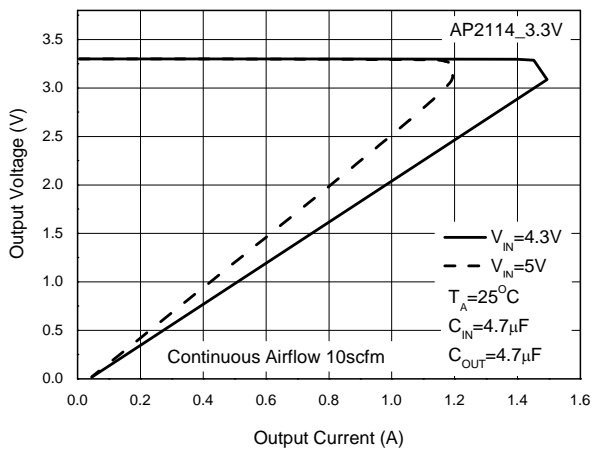


Figure 28. Output Voltage vs. Output Current

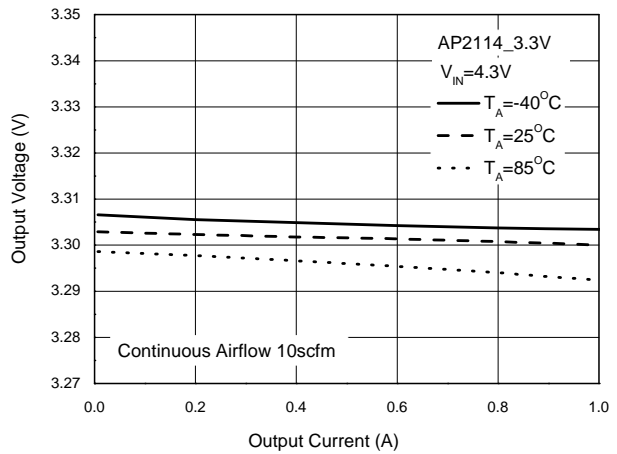


Figure 29. Output Voltage vs. Output Current

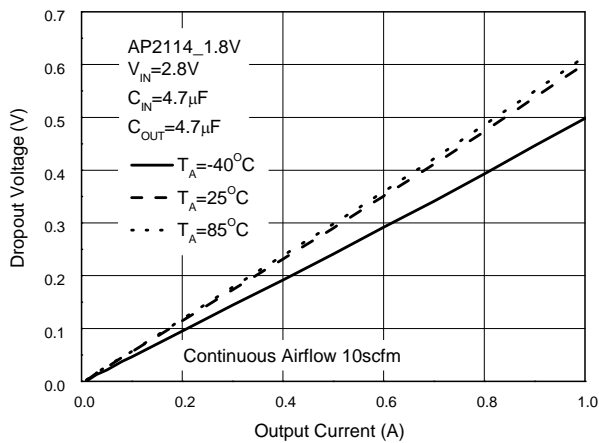


Figure 30. Dropout Voltage vs. Output Current

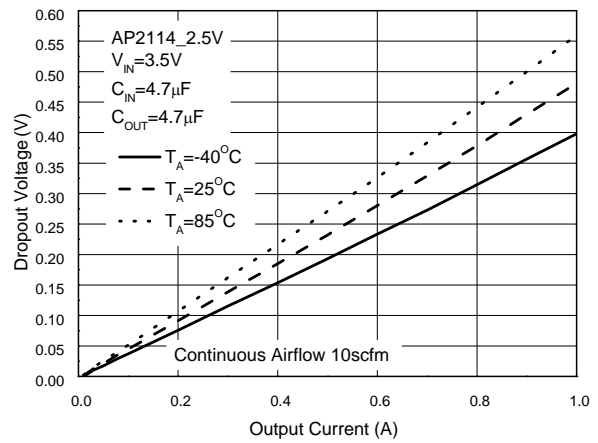


Figure 31. Dropout Voltage vs. Output Current

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

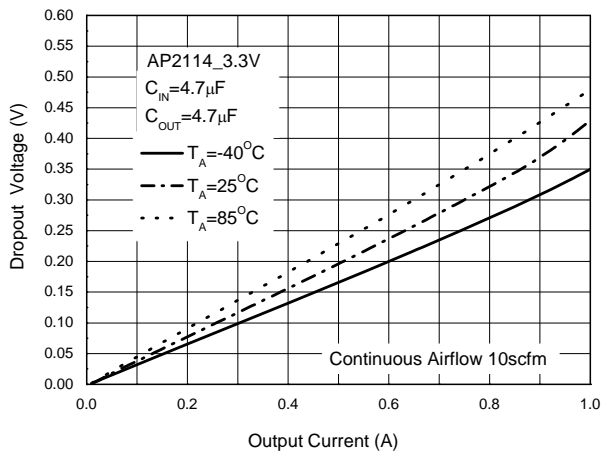


Figure 32. Dropout Voltage vs. Output Current

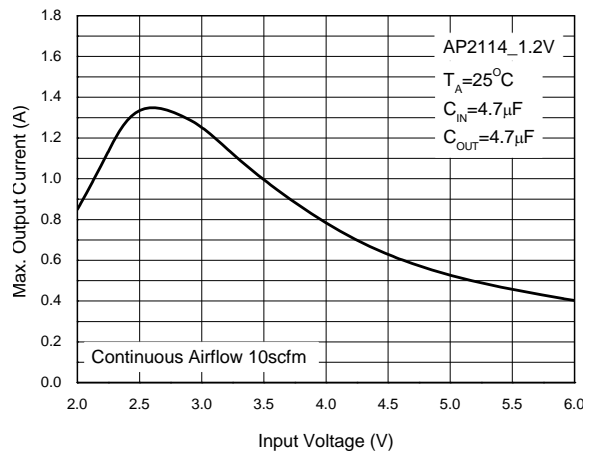


Figure 33. Max. Output Current vs. Input Voltage

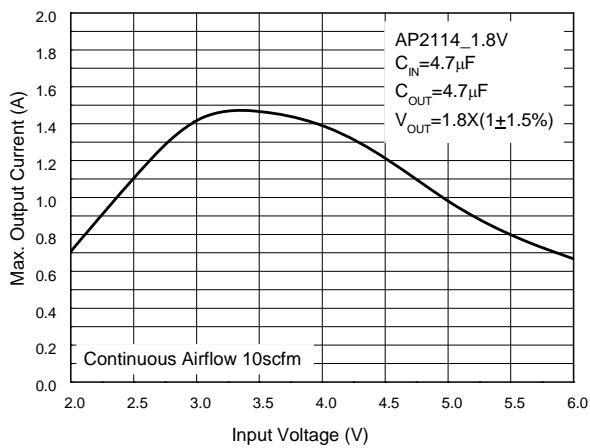


Figure 34. Max. Output Current vs. Input Voltage

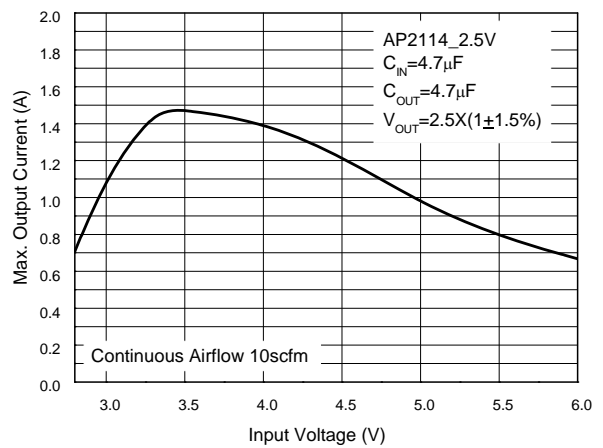


Figure 35. Max. Output Current vs. Input Voltage

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

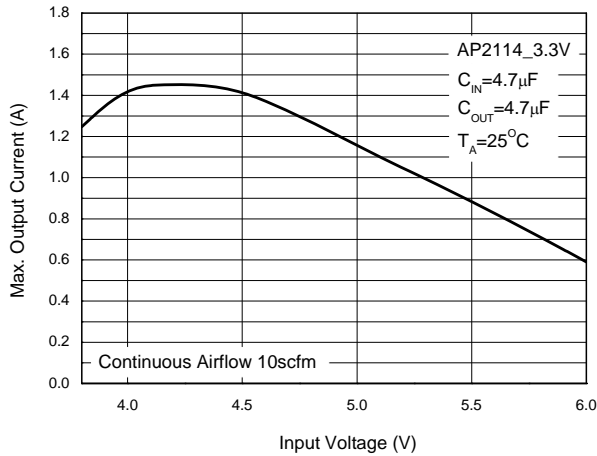


Figure 36. Max. Output Current vs. Input Voltage

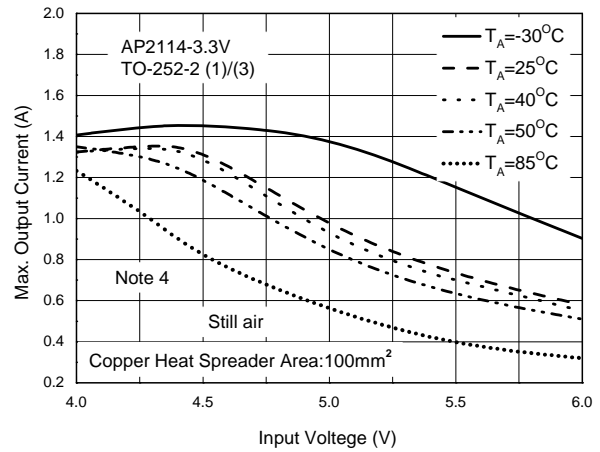


Figure 37. Max. Output Current vs. Input Voltage

Note 4: Considering power dissipation and thermal behavior, we suggest provide enough design margins in application design which are no less than 30% at least.

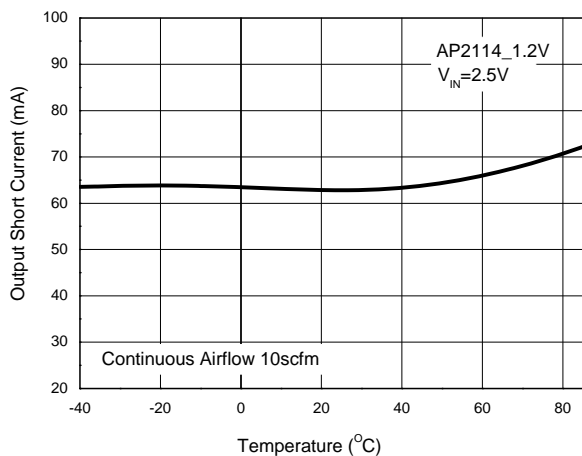


Figure 38. Output Short Current vs. Temperature

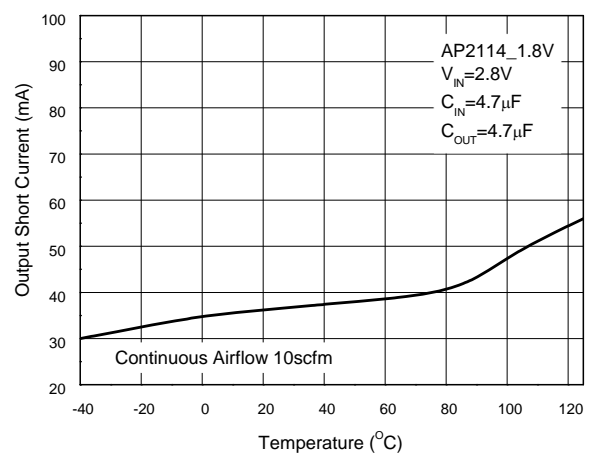


Figure 39. Output Short Current vs. Temperature

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

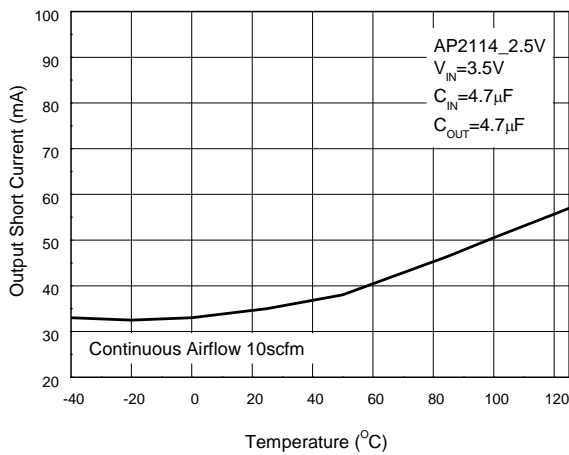


Figure 40. Output Short Current vs. Temperature

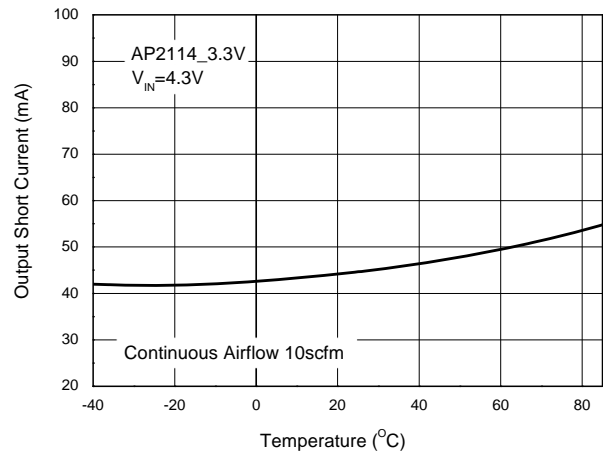


Figure 41. Output Short Current vs. Temperature

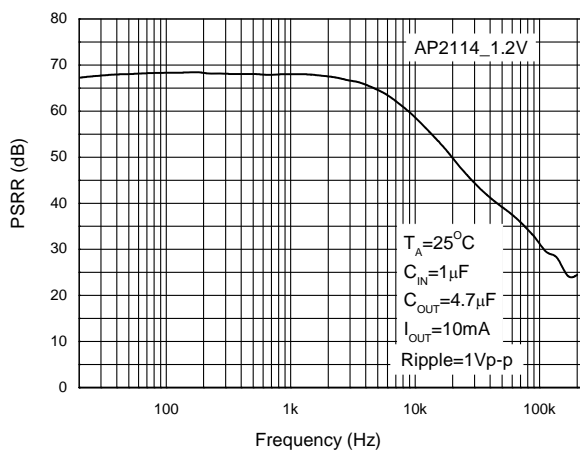


Figure 42. PSRR vs. Frequency

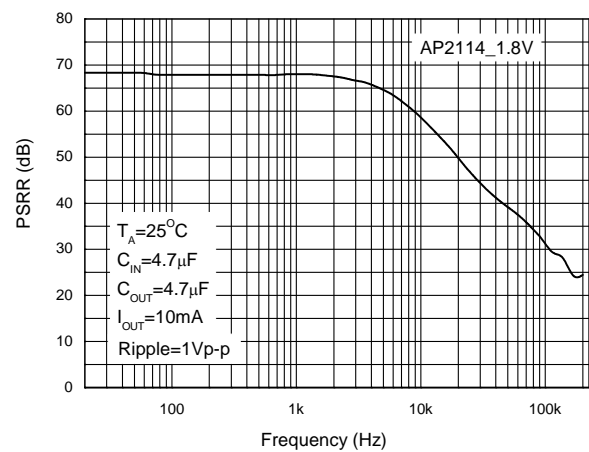


Figure 43. PSRR vs. Frequency

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Performance Characteristics (Continued)

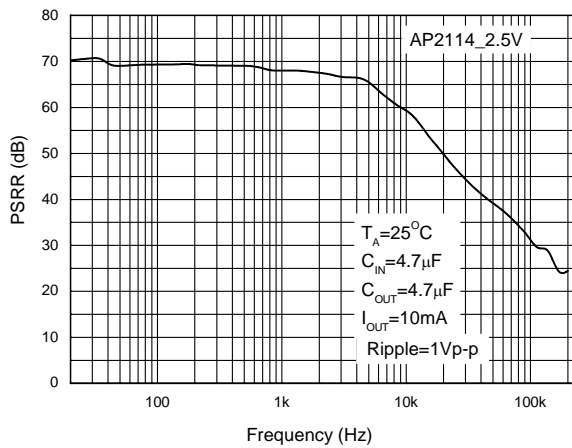


Figure 44. PSRR vs. Frequency

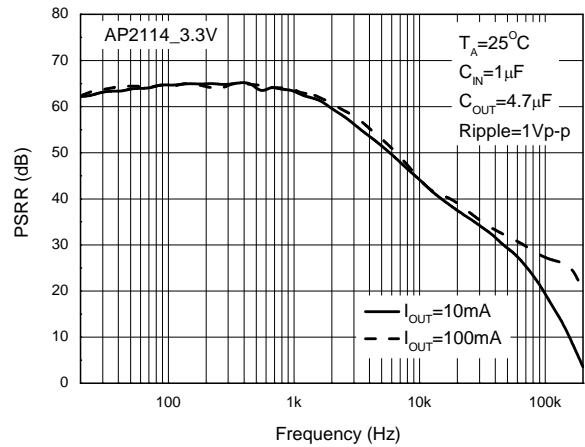


Figure 45. PSRR vs. Frequency

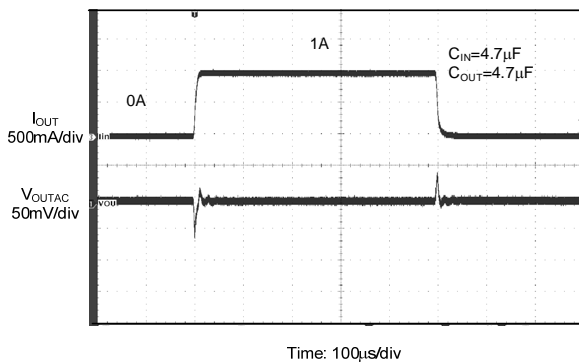


Figure 46. Load Transient

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Typical Application

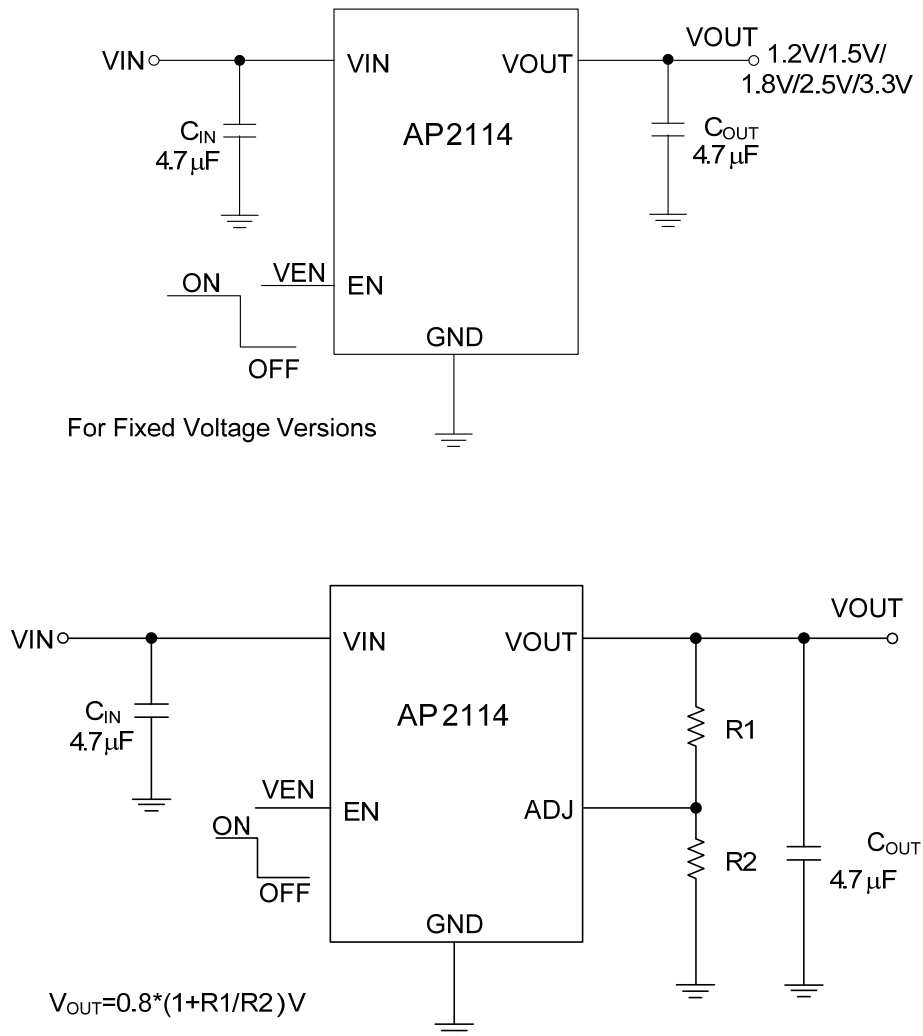


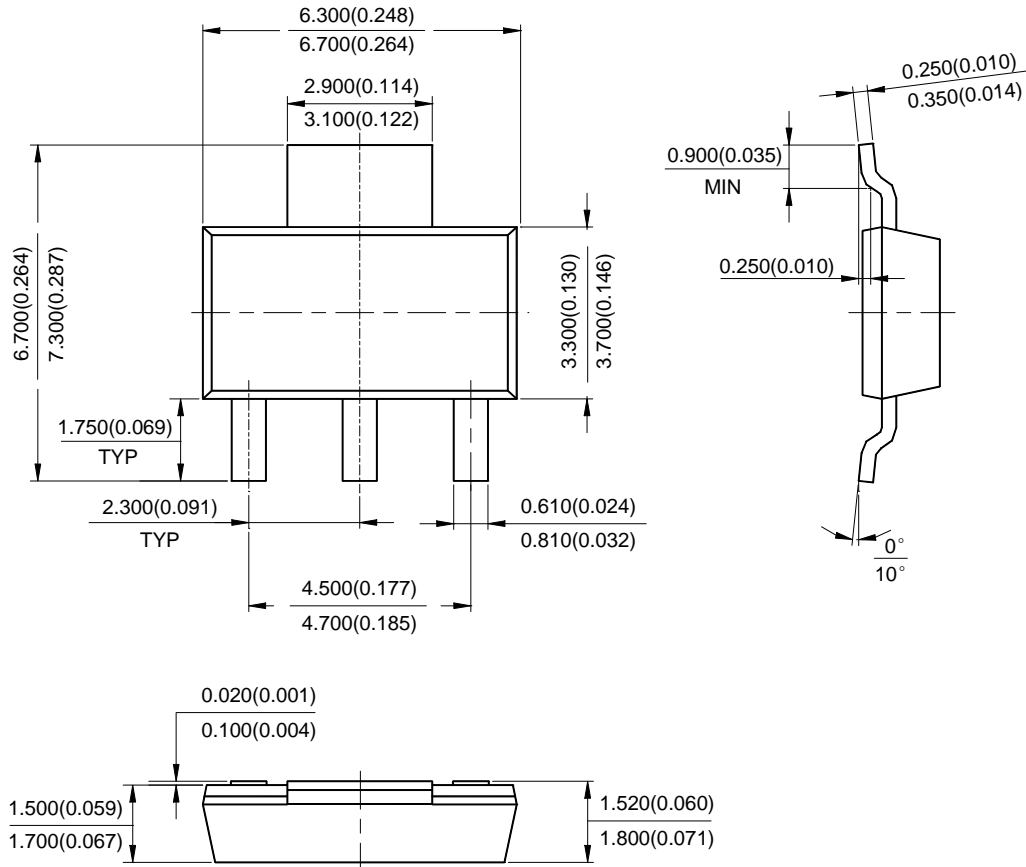
Figure 47. Typical Application of AP2114

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions

SOT-223

Unit: mm(inch)

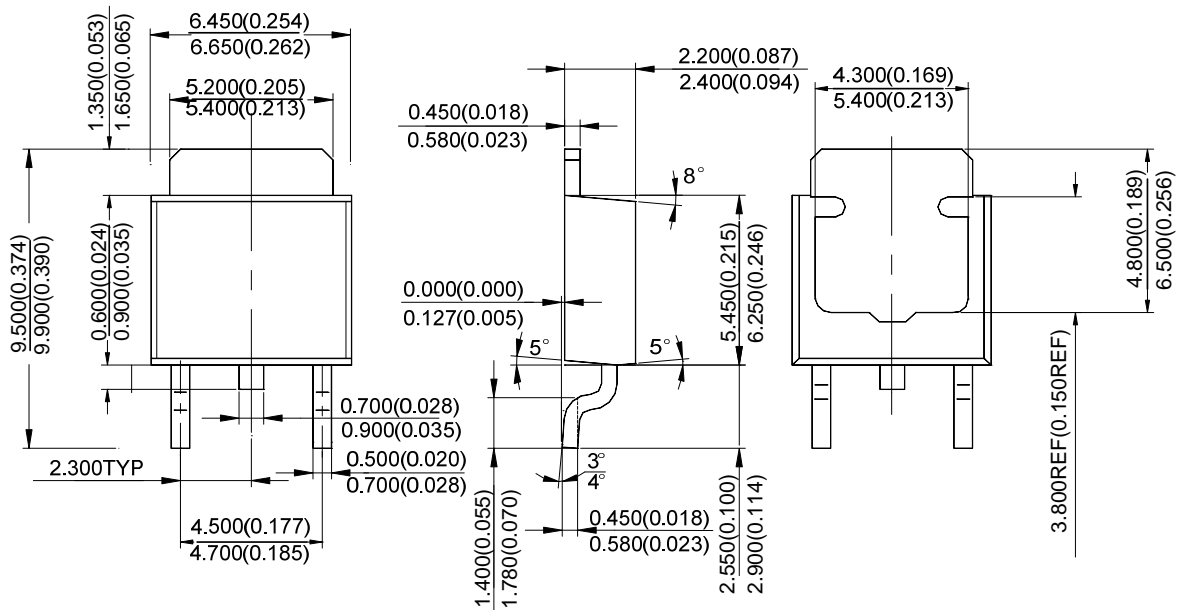


1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

TO-252-2 (1)

Unit: mm(inch)

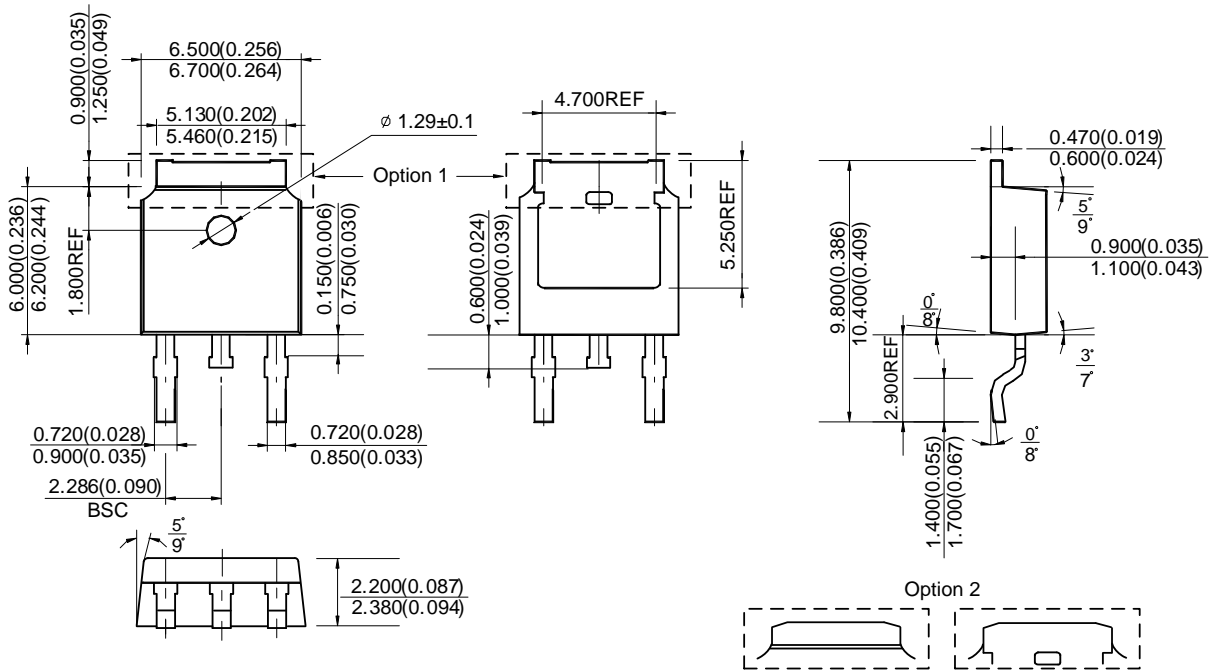


1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

TO-252-2 (3)

Unit: mm(inch)

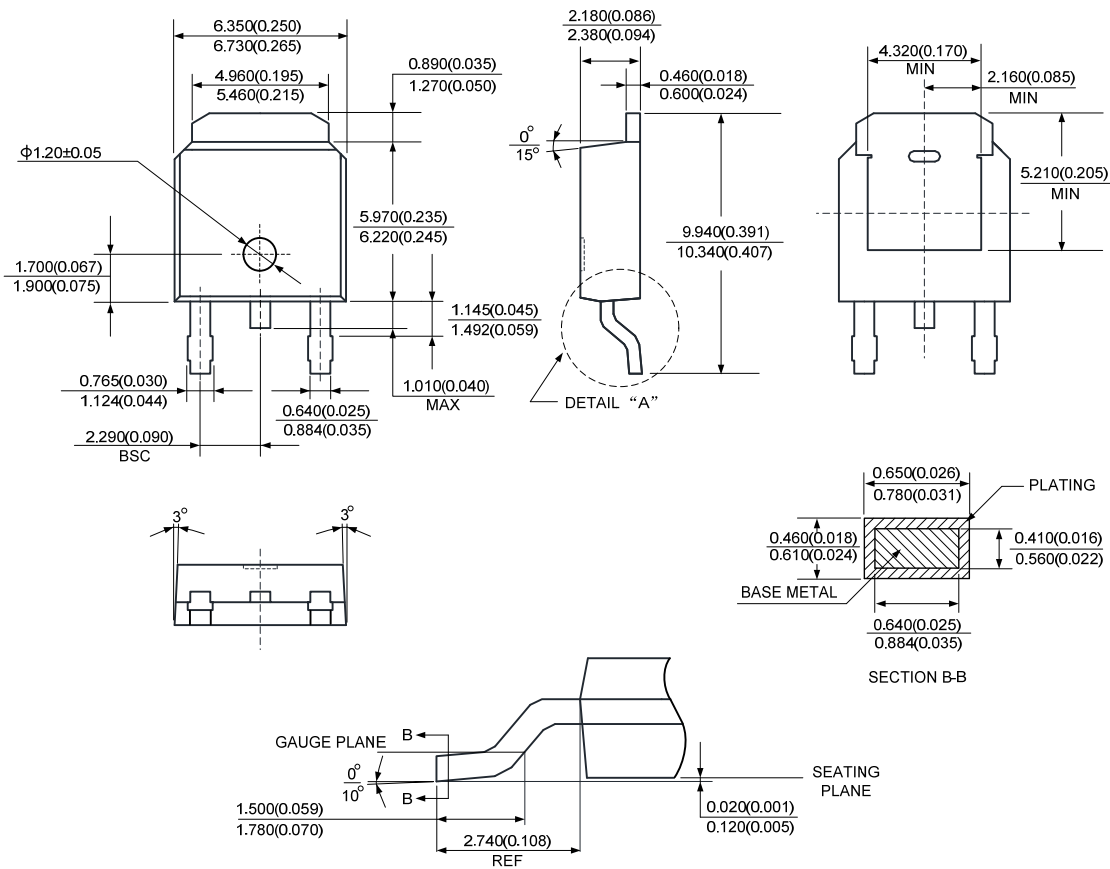


1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

TO-252-2 (4)

Unit: mm(inch)

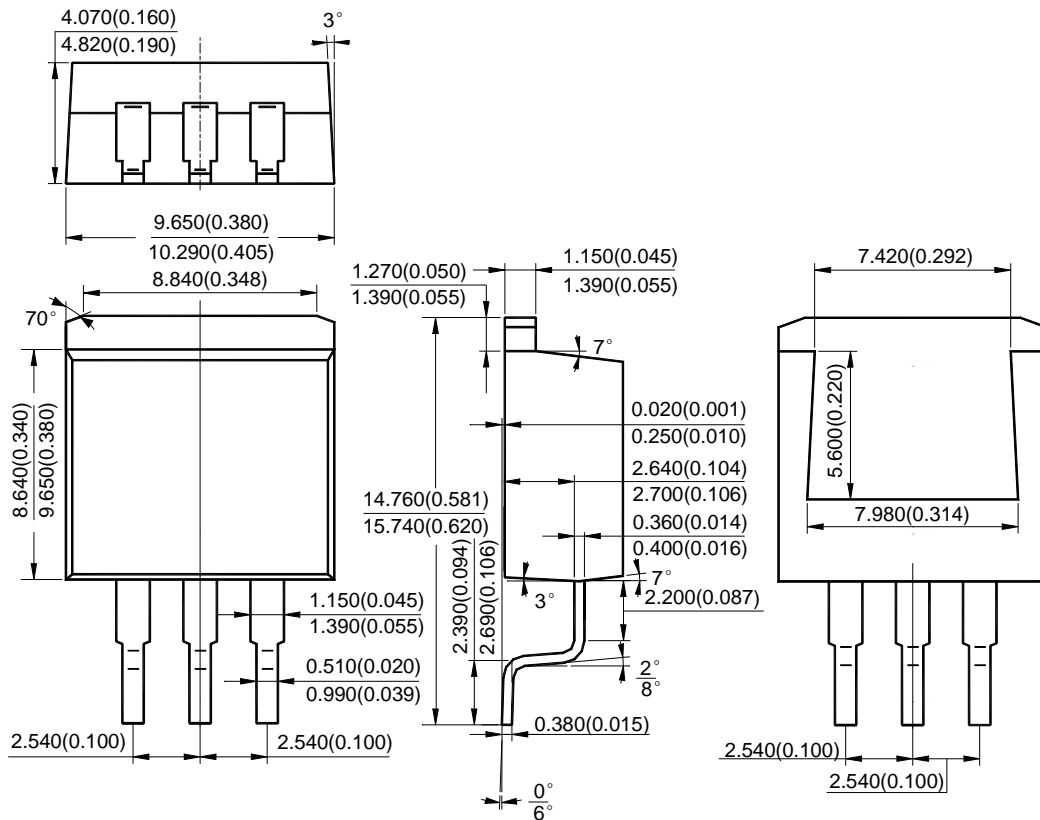


1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

TO-263-3

Unit: mm(inch)

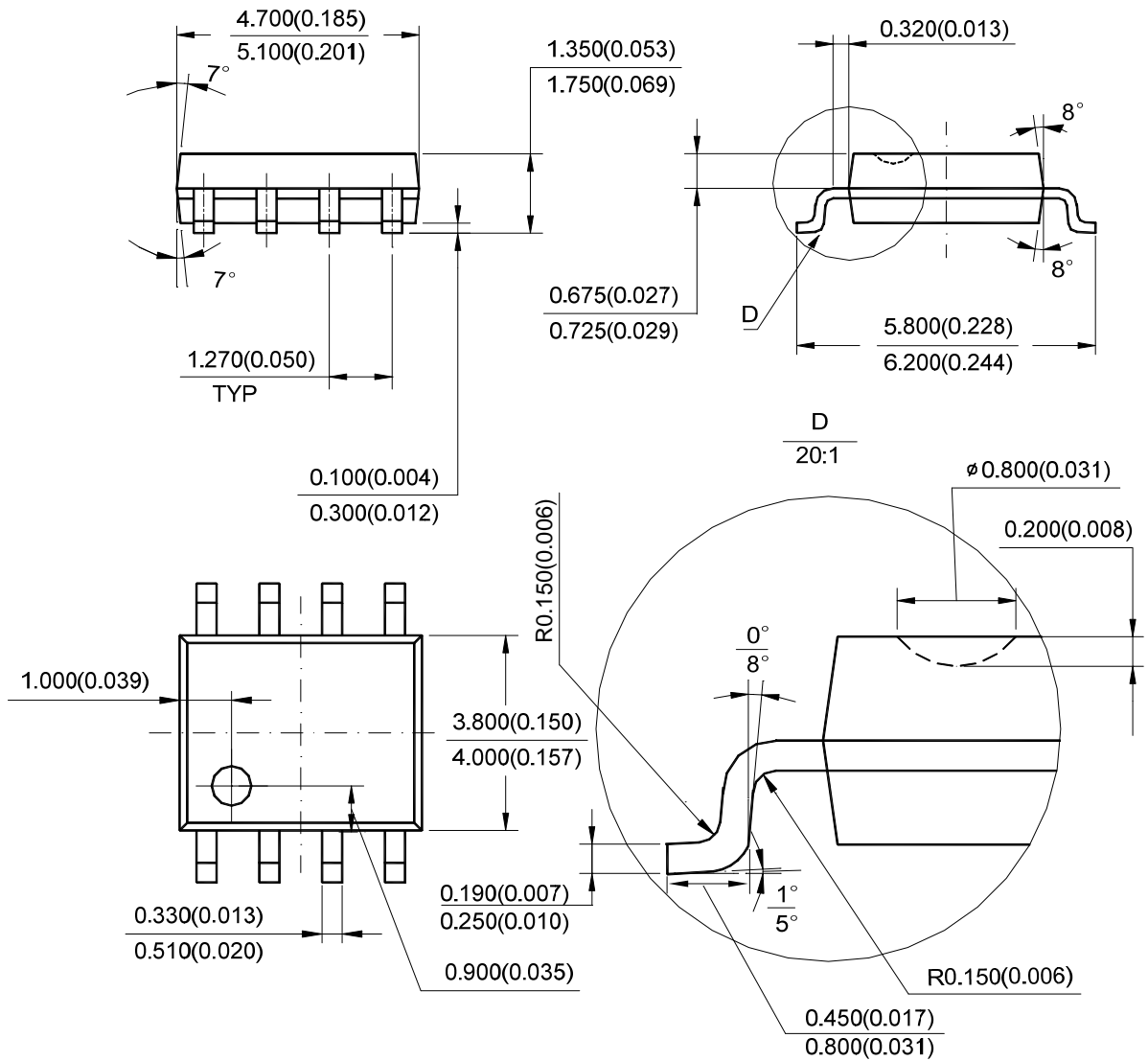


1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

SOIC-8

Unit: mm(inch)



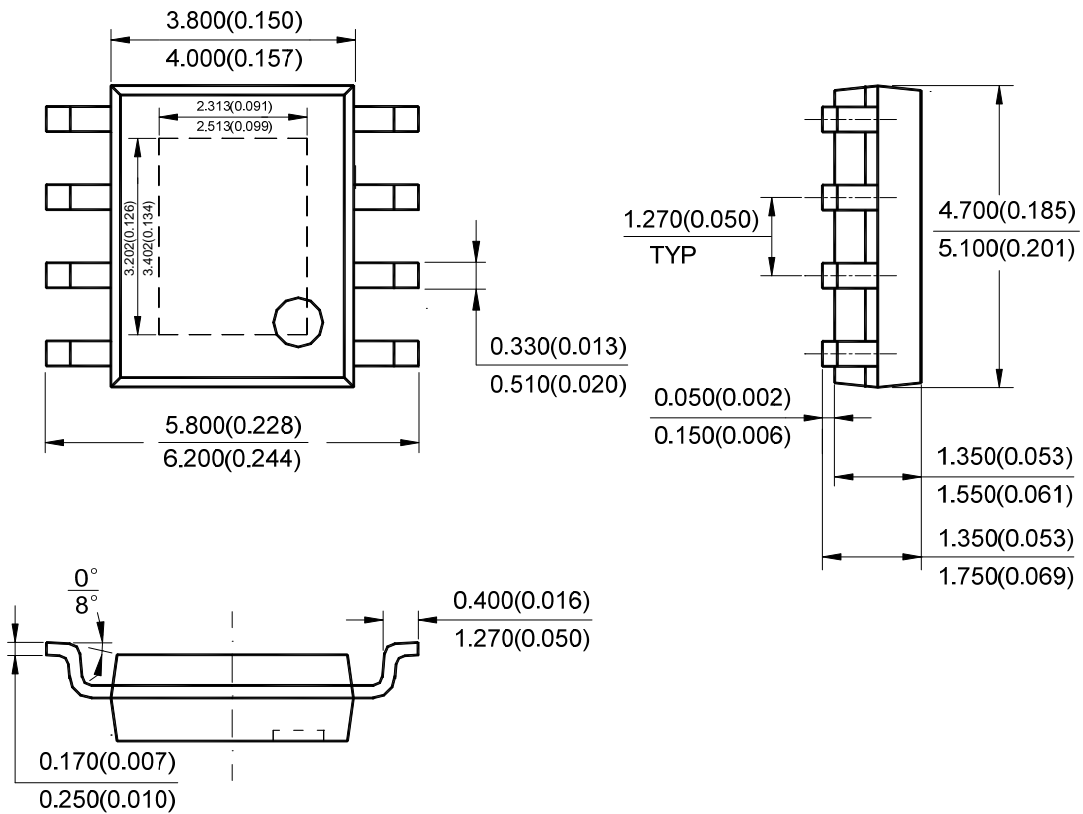
Note: Eject hole, oriented hole and mold mark is optional.

1A LOW NOISE CMOS LDO REGULATOR WITH ENABLE AP2114

Mechanical Dimensions (Continued)

PSOP-8

Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.



BCD Semiconductor Manufacturing Limited

<http://www.bcdsemi.com>

IMPORTANT NOTICE

BCD Semiconductor Manufacturing Limited reserves the right to make changes without further notice to any products or specifications herein. BCD Semiconductor Manufacturing Limited does not assume any responsibility for use of any its products for any particular purpose, nor does BCD Semiconductor Manufacturing Limited assume any liability arising out of the application or use of any its products or circuits. BCD Semiconductor Manufacturing Limited does not convey any license under its patent rights or other rights nor the rights of others.

MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China
Tel: +86-21-24162266, Fax: +86-21-24162277

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, China
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office

Unit A Room 1203, Skyworth Bldg., Gaoxin Ave. 1.S., Nanshan District, Shenzhen, China
Tel: +86-755-8826 7951
Fax: +86-755-8826 7865

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited

4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan
Tel: +886-2-2656 2808
Fax: +886-2-2656 2806

USA Office

BCD Semiconductor Corp.

30920 Huntwood Ave. Hayward, CA 94544, USA
Tel : +1-510-324-2988
Fax: +1-510-324-2788

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View AP2114D-1.2TRG1 on WIN SOURCE](#)
- ⊖ [Diodes Incorporated Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management